

Low Dropout Voltage Regulators

DESCRIPTION

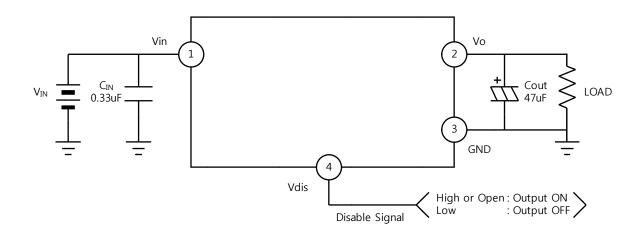
The ISP278R05 is a low-dropout voltage regulator suitable for various electronic equipments. Dropout voltage of ISP278R05 Series is below 0.5V in full rated current (1.6A).

Cause the series have been designed for high current loads, so they are also used in lower current, extremely low dropout-critical systems (in which their tiny dropout voltage and ground current values are important attributes).

FEATURES

- IOUT=1.6A; VOUT=5V
- TO-220 Full Mold Package (4 pin)
- Internal over current protection, internal thermal shutdown
- Internal overvoltage protection, internal short-circuit protection
- Output disable function

Typical Application Circuit

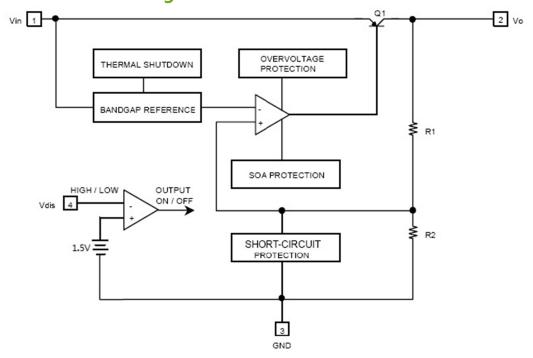




Maximum Ratings

Characteristic	Symbol	Rating	Units
Input Voltage	VI	18	V
Control Input Voltage	VcT	18	V
Danier Dissipation	Pd1(No Heat sink)	1.5	W
Power Dissipation	Pd2(With Heat sink)	15	W
Junction Temperature	TJ.	150	οС
Operating Temperature Range	Topr	-20 ~ 80	°C
Storage Temperature Range	Tstg	-50 ~ 150	°C
Thermal shutdown Temperature	Ttsd	150	°C

Internal Block Diagram





Package Information



Package	Pin Info.		
(TO-220F-4L)	1.Vin 2.Vout 3.GND 4.Vdis		

Ordering Information

Part No	Package	Packing	Finish	Halogen	Packing Unit	Remark
ISP278R05	TO-220F-4L	Tube	Sn	Free	5,000	

ISP278R05



Electrical Characteristics

Operating Conditions: VI =7V, Io = 1A, VcT(High)=2.7V, Ta = 25°C, unless otherwise specified

Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Output Voltage	Vo	ISP278R05 V:=6V~12V	4.88	5.0	5.12	V
Line Regulation	△Vo(△VI)	Note, Io=1.0A	-	0.5	2.5	%
Load Regulation	$\triangle V_{O(\triangle IL)}$	5mA≤lo≤2.0A	-	0.2	2.0	%
Quiescent Current	Iqc	Io=0mA	-	-	10	mA
Ripple Rejection Ratio	RR	(Vo+2V)≤VI≤12V, Io=50mA f=120Hz	45	55	-	dB
Dropout Voltage	VDROP	Io=1.0A	-	-	0.3	V
Dropout Voltage		Io=2.0A	-	-	0.5	V
Control Voltage High	VCT(High)	Io=0mA, Output ON	2.0	-	-	V
Control Voltage Low	VCT(Low)	Io=0mA, Output OFF	-	-	8.0	V
Disable Bias Current H	IdisH	Vdis=2.7V	-	-	20	uA
Disable Bias Current L	IdisL	Vdis=0.4V			-0.4	mA

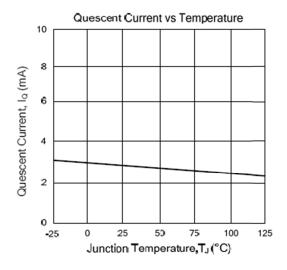
Notes

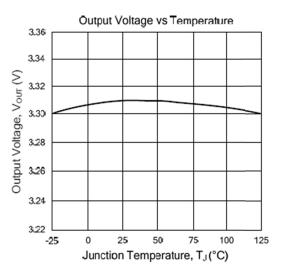
- 1. These parameters, although guaranteed, are not 100% tested in production.
- 2. Junction -to -case thermal resistance test environments.
- -. Pneumatic heat sink fixture.
- -. Clamping pressure 60psi through 12mm diameter cylinder.
- -. Thermal grease applied between PKG and heat sink fixture
- 3. Connect V_{CT} to V_{IN} when not using V_{CT} pin.

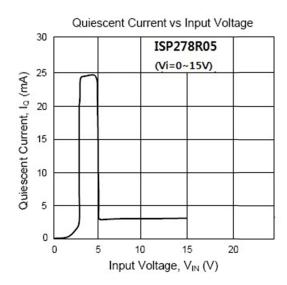
ISP278R05

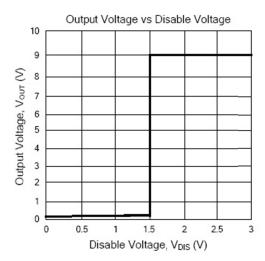


Electrical Characteristics Curves



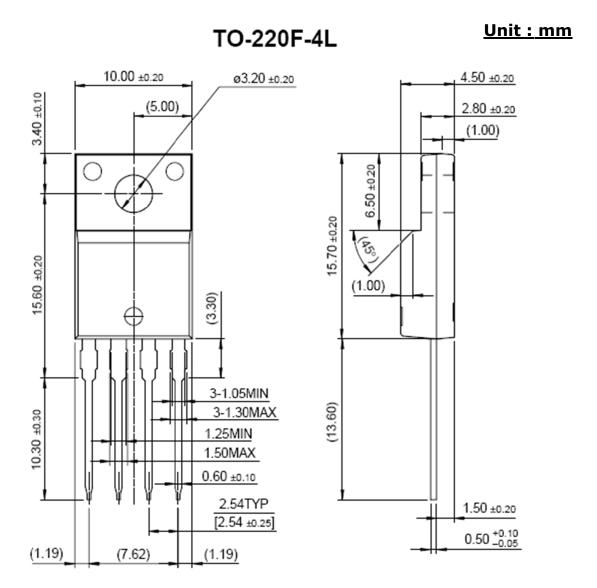








Package Dimension



ISP278R05



Revision History

No	Date	Contents		
1	2015-01-30	Initial Brief Datasheet Release		
2	2015-06-22	Added Ttsd ability (150°C)		



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AP Semiconductor Co., Ltd

Contact. Tel 82.70.4693.2299 FAX 82.70.4000.4009

E-mail: sales@apsemi.com

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